NSN 5962-01-420-9599

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View Online at https://aerobasegroup.com/nsn/5962-01-420-9599 **Body Length:** 0.358 inches **Body Width:** 0.358 inches **Body Height:** 0.100 inches **Maximum Power Dissipation Rating:** 550.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Pacer dawn **Features Provided:** Hermetically sealed and burn in and programmable and positive outputs and electrostatic sensitive **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 16 input **Criticality Code Justification:** Cbbl **Case Outline Source And Designator:** G-2 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output **Memory Device Type: Terminal Type And Quantity:** 20 leadless

N/a

Shelf Life:

Unit Of Measure:

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Der	nilit	ariz	atio	n:

No

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